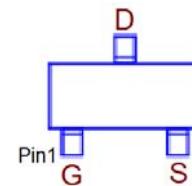
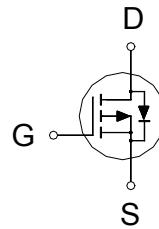


NIKO-SEM
**P-Channel Enhancement Mode
Field Effect Transistor**
**PM509BA
SOT-23(S)
Halogen-Free & Lead-Free**
**PRODUCT SUMMARY**

$V_{(BR)DSS}$	$R_{DS(ON)}$	I_D
-30V	120mΩ	-2A


G. GATE
D. DRAIN
S. SOURCE
ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ Unless Otherwise Noted)

PARAMETERS/TEST CONDITIONS	SYMBOL	LIMITS	UNITS
Drain-Source Voltage	V_{DS}	-30	V
Gate-Source Voltage	V_{GS}	±20	V
Continuous Drain Current	I_D	-2	A
		-1.5	
Pulsed Drain Current ¹	I_{DM}	-8	
Power Dissipation	P_D	0.7	W
		0.4	
Operating Junction & Storage Temperature Range	T_j, T_{stg}	-55 to 150	°C

THERMAL RESISTANCE RATINGS

THERMAL RESISTANCE	SYMBOL	TYPICAL	MAXIMUM	UNITS
Junction-to-Ambient ²	$R_{\theta JA}$		177	°C/W

¹Pulse width limited by maximum junction temperature.²The value of $R_{\theta JA}$ is measured with the device mounted on 1in² FR-4 board with 2oz. Copper.**ELECTRICAL CHARACTERISTICS ($T_j = 25^\circ\text{C}$, Unless Otherwise Noted)**

PARAMETER	SYMBOL	TEST CONDITIONS	LIMITS			UNIT
			MIN	TYP	MAX	
STATIC						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = -250\mu\text{A}$	-30			V
Gate Threshold Voltage	$V_{GS(\text{th})}$	$V_{DS} = V_{GS}, I_D = -250\mu\text{A}$	-1	-1.7	-3	
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0V, V_{GS} = \pm 20V$			±100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = -24V, V_{GS} = 0V$			-1	μA
		$V_{DS} = -20V, V_{GS} = 0V, T_j = 55^\circ\text{C}$			-10	
On-State Drain Current ¹	$I_{D(\text{ON})}$	$V_{DS} = -10V, V_{GS} = -10V$	-8			A
Drain-Source On-State Resistance ¹	$R_{DS(\text{ON})}$	$V_{GS} = -4.5V, I_D = -1.5A$		134	180	$\text{m}\Omega$
		$V_{GS} = -10V, I_D = -2A$		98	120	

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Forward Transconductance ¹	g_{fs}	$V_{DS} = -5V, I_D = -2A$		4.3		S
DYNAMIC						
Input Capacitance	C_{iss}	$V_{GS} = 0V, V_{DS} = -15V, f = 1MHz$		190		pF
Output Capacitance	C_{oss}			36		
Reverse Transfer Capacitance	C_{rss}			27		
Total Gate Charge ²	Q_g			4.8		
Gate-Source Charge ²	Q_{gs}	$V_{DS} = -15V, V_{GS} = -10V, I_D = -2A$		0.5		nC
Gate-Drain Charge ²	Q_{gd}			1.3		
Turn-On Delay Time ²	$t_{d(on)}$			14		
Rise Time ²	t_r			36		
Turn-Off Delay Time ²	$t_{d(off)}$	$V_{DD} = -15V, V_{GS} = -10V$ $I_D \geq -2A, R_G = 6\Omega$		42		nS
Fall Time ²	t_f			34		
SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS ($T_J = 25^\circ C$)						
Continuous Current	I_S			-2	A	
Forward Voltage ¹	V_{SD}	$I_F = -2A, V_{GS} = 0V$		-1.1	V	
Reverse Recovery Time	t_{rr}	$I_F = -2A, dI_F/dt = 100A / \mu S$		15		nS
Reverse Recovery Charge	Q_{rr}			8		nC

¹Pulse test : Pulse Width $\leq 300 \mu sec$, Duty Cycle $\leq 2\%$.

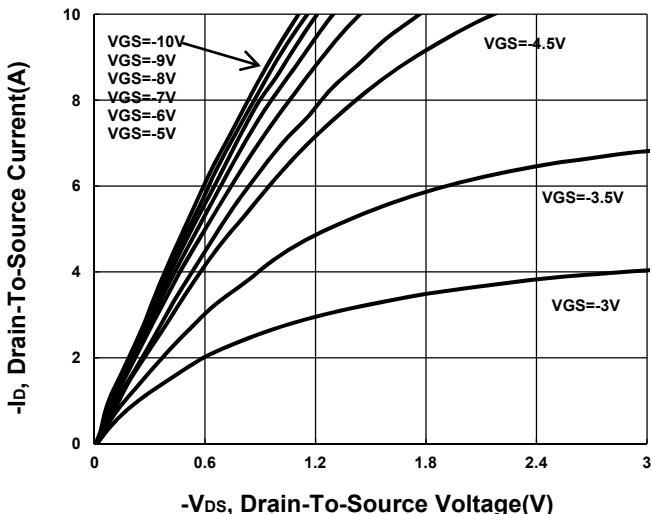
²Independent of operating temperature.

NIKO-SEM

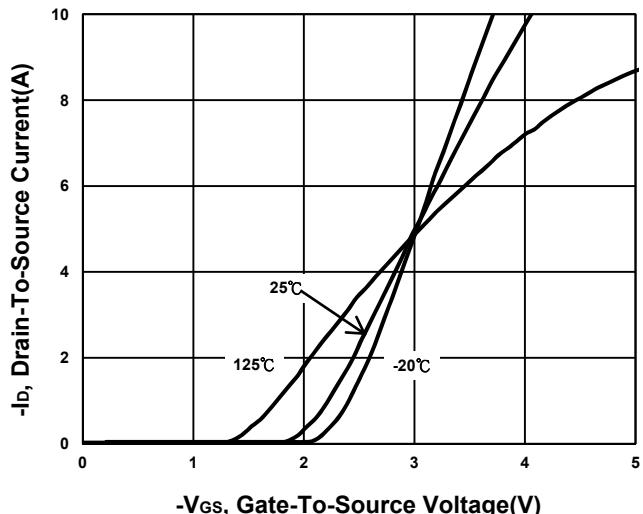
**P-Channel Enhancement Mode
Field Effect Transistor**

PM509BA
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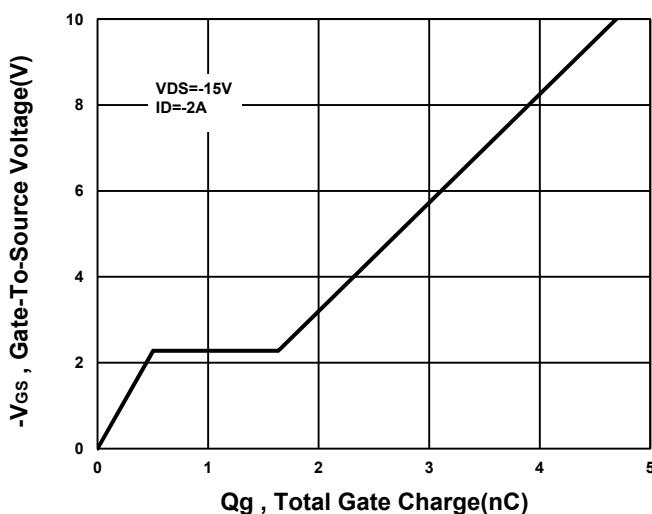
Output Characteristics



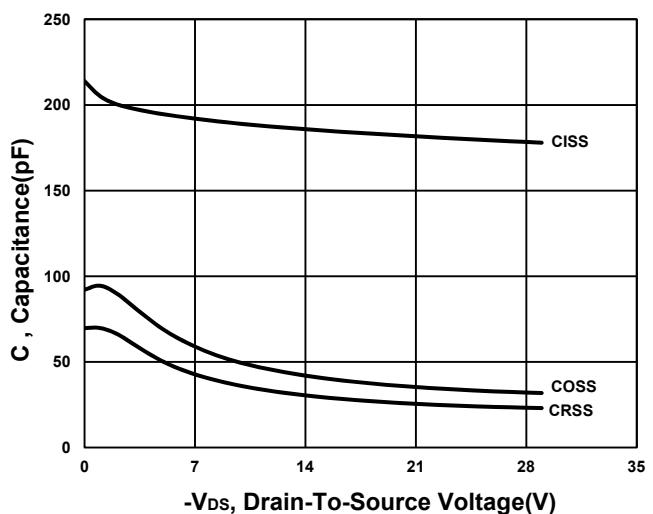
Transfer Characteristics



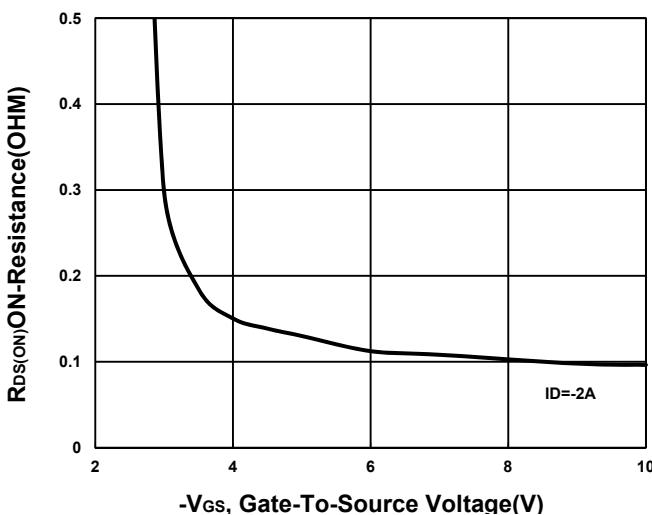
Gate charge Characteristics



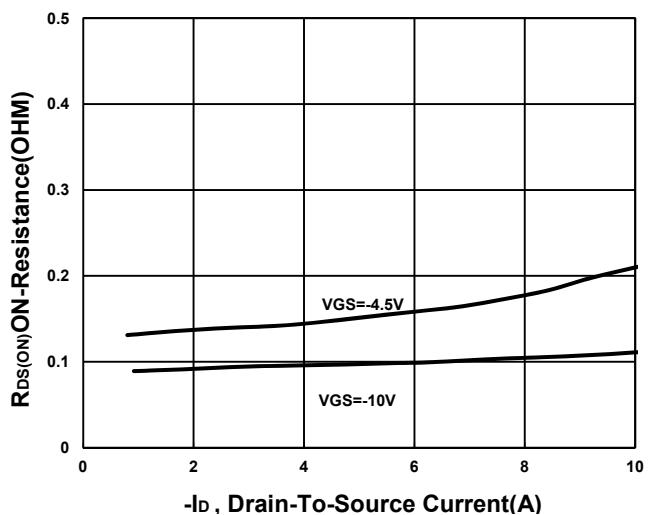
Capacitance Characteristic

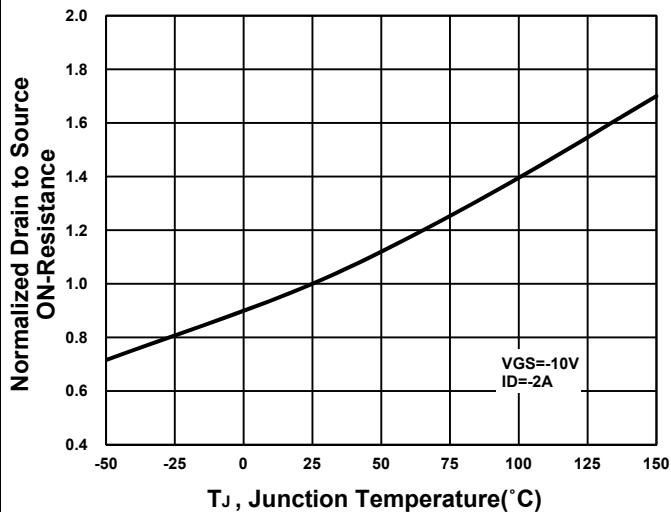
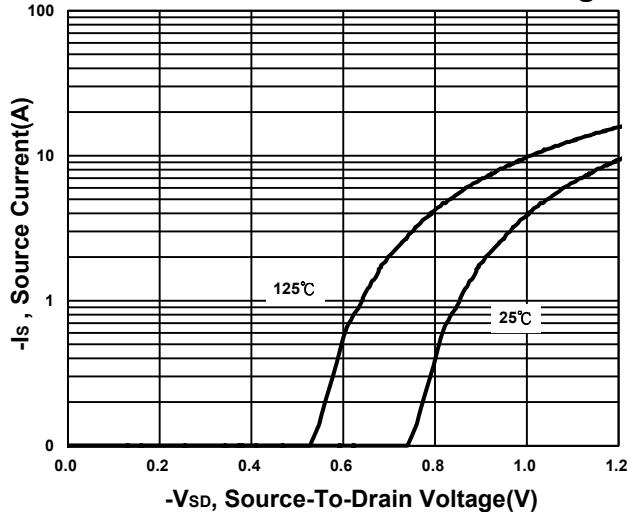
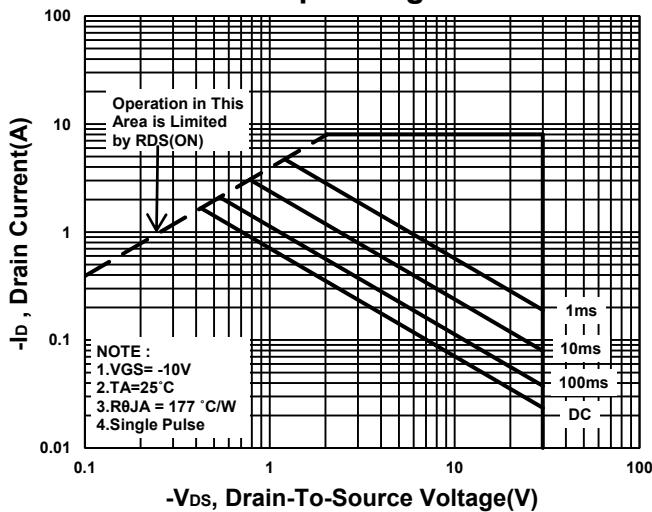
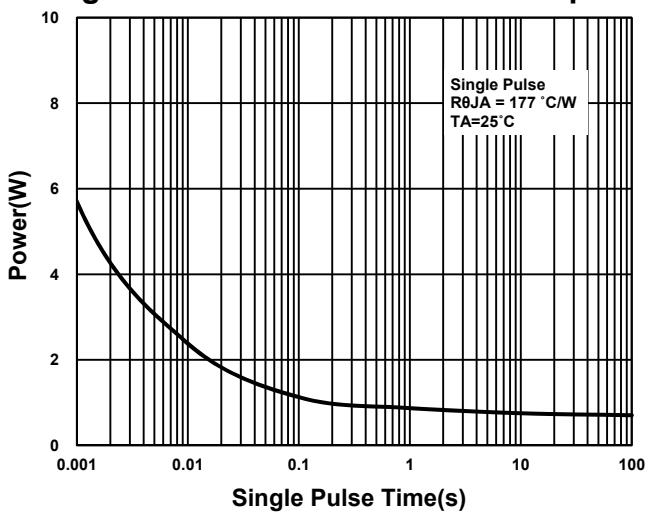
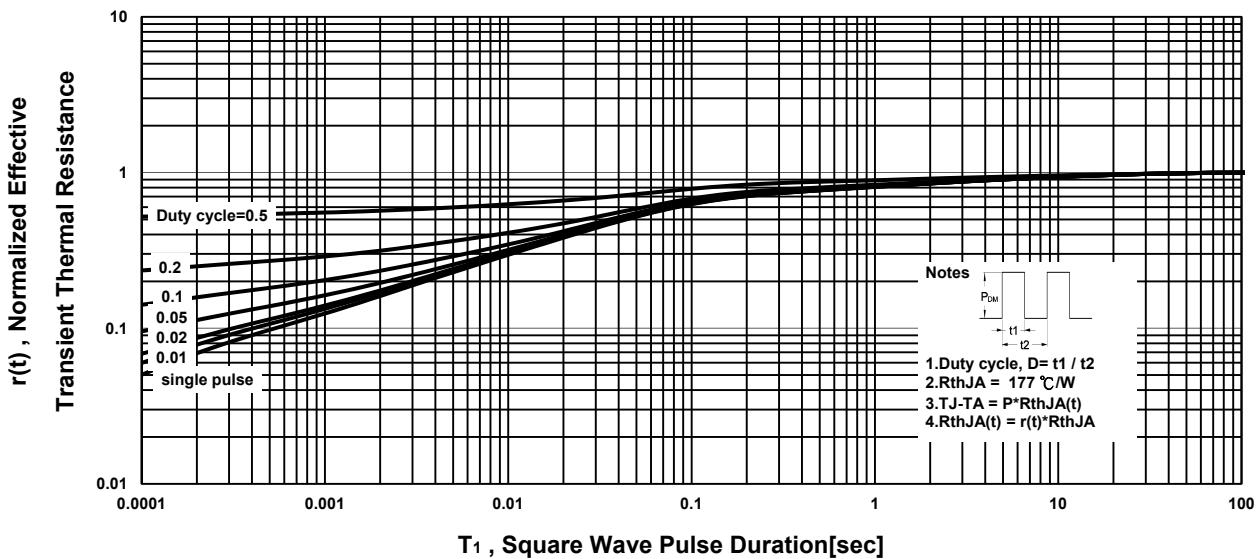


On-Resistance VS Gate-To-Source



On-Resistance VS Drain Current



NIKO-SEM**P-Channel Enhancement Mode
Field Effect Transistor****PM509BA
SOT-23(S)
Halogen-Free & Lead-Free****On-Resistance VS Temperature****Source-Drain Diode Forward Voltage****Safe Operating Area****Single Pulse Maximum Power Dissipation****Transient Thermal Response Curve**

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